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Fairchild Semiconductor BC318C

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September 2007

BC318C PNP Epitaxial Silicon Transistor

- This device is designed for general purpose amplifier application at collector currents to 800m/
- Sourced from process 38.



Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	20	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	100	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ 150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06".

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = 10μA	30			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 1mA	20			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 100μA	5			V
BV _{CES}	Collector-Emitter Breakdown Voltage	I _C = 100μA	30			V
I _{CBO}	Collector Cut-off Current	V _{CB} = 20V T = 25 °C T = 100 °C			30 15	nA μA
h _{FE}	DC Current Gain	$V_{CE} = 5V, I_{C} = 10 \mu A$ $V_{CE} = 5V, I_{C} = 2 mA$	100 420		800	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ $I_C = 100 \text{ mA}, I_B = 5 \text{ mA}$			0.2 0.5	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 5V, I_{C} = 2m$ $V_{CE} = 5V, I_{C} = 10mA$	0.57		0.72 0.77	V
C _{cb}	Output Capacitance	VCB = 10V, IE = 0, f = 1MHz			4	pF

- 1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.
- These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.These ratings are based on a maximum junction temperature of 150degrees C.

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

²⁾ These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

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Datasheet of BC318C - TRANS PNP 20V 0.1A TO-92

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Rev. I30